2.1A Power Switch with Programmable Current Limit

General Description

The LPW5209 is an integrated power switch for self-powered and bus-powered Universal Series Bus (USB) applications. A built-in charge pump is used to drive the N-Channel MOSFET that is free of parasitic body diode to eliminate any reversed current flow across the switch when it is powered off. Its low quiescent current (16µA) and small package (SOT23-5) is particularly suitable in battery-powered portable equipment.

Several protection functions include soft start to limit inrush current during plug-in, current limiting at 2.1A to meet USB power requirement, and thermal shutdown to protect damage under over current conditions.

Features

- $80m\Omega$ Low $R_{DS(ON)}$, High-side N-MOSFET
- 2100mA Programmable current limit
- 2.5V to 6V Input Voltage
- Low Quiescent Current:30µA
- Soft Start Function
- **Built-In Short-Circuit Protection**
- **Built-in Thermal Protection**
- RoHS Compliant and 100% Lead (Pb)-Free

Typical Application Circuit

Order Information \[\lambda \] \[\mathbb{W} \mathbb{P} \mathbb{W} \mathbb{P} \mathbb{W} \mathbb{P} \mathbb{W} \mathbb{P} \mathbb{W} \mathbb{P} \mathbb{M} \mathbb{M} \mathbb{P} \mathbb{M} \mathbb{M} \mathbb{P} \mathbb{M} \mathbb{M} \mathbb{P} \mathbb{M} \mathbb{M} \mathbb{M} \mathbb{P} \mathbb{M} M					
Ordering Number	Current	Package			
LPW5209AB5F	Adjustable				
LPW5209B5F-21	2.1A	COT22 F			
LPW5209B5F-11	1.1A	SOT23-5			
LPW5209B5F-06	600mA				

VIN VOUT LPW5209B5F-Adi VIN Cout **GND RSET** 2 Riset 6.8K

Applications

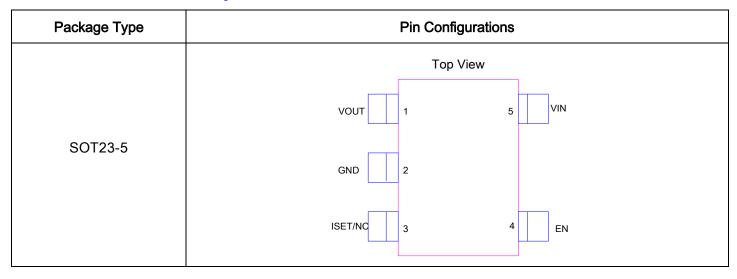
- Power Switch
- **USB** Device
- **Battery Charger Circuits**

Marking Information

Device	Marking	Shipping			
LPW5209AB5F	LPS				
LPW5209AB5F	C0YWX				
L DIMESONDEE OA	LPS				
LPW5209B5F-21	C1YWX	3K/REEL			
L DIMESOOREE 44	LPS	3N/REEL			
LPW5209B5F-11	C2YWX				
LPW5209B5F-06	LPS				
LPVV5209B5F-00	C3YWX				
Marking indication:					
Y:Production year \	W:Production week	X:Production batch			

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Functional Pin Description

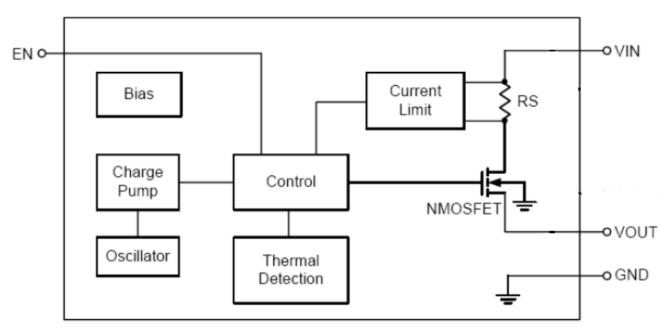


Pin Description

Nome	Pin		Description	
Name	LPW5209A	LPW5209-21/11/06	Description	
VOUT	1 D Somi	1	Output to system pin.	
GND	2	2	Ground.	
ISET	3	LowDowon@	Connect a resistor to GND for setting current limit.	
NC		<u> </u>	No connecter	
EN	4	4	Device Enable (active High).	
VIN	5	5	Input pin.	

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Function Block Diagram



Absolute Maximum Ratings Note

	Input Voltage to GND 7V
	Output Voltage to GND 7V
	Other pin to GND 6V
	Maximum Junction Temperature 150°C
	Operating Ambient Temperature Range (T _A)
	Maximum Soldering Temperature (at leads, 10 sec) 260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

- ♦ Maximum Power Dissipation (SOT23-5, P_D, T_A=25°C) ----- 0.45W
- ♦ Thermal Resistance (SOT23-5, θ_{JA}) ------ 250°C/W

ESD Susceptibility

- ♦ HBM(Human Body Mode) ------ 2KV
- ♦ MM(Machine Mode) ------ 200V

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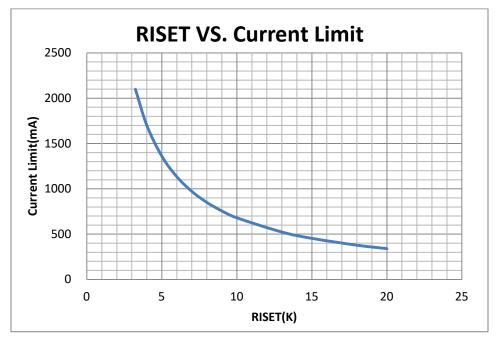
Electrical Characteristics

(Over recommended operating conditions unless specified otherwise, T_A=25°C)

Symbol	Parameter	Condition	Min	Тур	Max	Units	
V_{IN}	Input Voltage		2.5		6	V	
	Output Current Limit	LPW5209B5F-Adj,R _{ISET} =10K		680			
		PW5209B5F-Adj,R _{ISET} =6.8K		1000			
1		PW5209B5F-Adj,R _{ISET} =3.4K		2000			
lоuт		LPW5209B5F-21		2100		mA	
		PW5209B5F-11		1100			
		PW5209B5F-06		600			
R _{DS(ON)}	Output N-MOSFET RDS(ON)	lout=1A		80	100	mΩ	
ΙQ	Quiescent Current	V _{IN} =3V		30	50	μA	
I _{SHDN}	Shutdown Current	V _{EN} =GND		0.1	1	μA	
V _{EN(L)}	Enable Threshold Low				0.4	V	
V _{EN(H)}	Enable Threshold High		1.4			V	
I _{EN}	Input High Current	V _{IN} =V _{EN} =5.0V	上道	5		μA	
ОТР	Over temperature protection	TOGILL INAMA		150		°C	
OTP-HYS	Over temperature hysteresis			20		°C	

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Typical Operating Characteristics





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Preliminary Datasheet

LPW5209

Application Information

The LPW5209 are single N-Channel MOSFET high-side power switches with active-high enable input, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications. The LPW5209 equipped with a charge pump circuitry to drive the internal NMOS switch; the switch's low RDS(ON), $80m\Omega$, meets USB voltage drop requirements.

Input and Output

VIN (input) is the power source connection to the internal circuitry and the drain of the MOSFET. VOUT (output) is the source of the MOSFET. In a typical application, current flows through the switch from VIN to VOUT toward the load. If VOUT is greater than VIN, current will flow from VOUT to VIN since the MOSFET is bidirectional when on. Unlike a normal MOSFET, there is no a parasitic body diode between drain and source of the MOSFET, the LPW5209 prevents reverse current flow if VOUT being externally forced to a higher voltage than VIN when the output disabled (VEN < 0.4V).

Chip Enable Input

The switch will be disabled when the EN pin is in a logic low condition. During this condition, the internal circuit is turned off, reducing the supply current to 0.1µA typical. The maximum guaranteed voltage for a logic low at the EN pin is 0.4V. A minimum guaranteed voltage of 1.4V at the EN pin will turn the LPW5209 back on. Floating the input may cause unpredictable operation. EN should not be allowed to go negative with respect to GND. The EN pin may be directly tied to VIN to keep the part on.

Soft Start for Hot Plug-In Applications

In order to eliminate the upstream voltage droop caused by the large inrush current during hot-plug events, the "soft-start" feature effectively isolates the power source from extremely large capacitive loads, satisfying the USB voltage droop requirements.

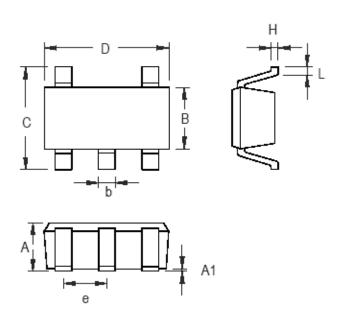
Thermal Shutdown

Thermal shutdown is employed to protect the device from damage if the die temperature exceeds approximately 150°C. If enabled, the switch automatically restarts when the die temperature falls 20°C. The output will continue to cycle on and off until the device is disabled or the fault is removed.

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Packaging Information

SOT23-5



Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.889	1.295	0.035	0.051	
A1	0.000	0.152	0.000	0.006	
В	1.397	1.803	0.055	0.071	
b	0.356	0.559	0.014	0.022	
С	2.591	2.997	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.838	1.041	0.033	0.041	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

SOT-23-5 Surface Mount Package

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